

**2SC3504**

High-Definition CRT Display, Video Output Applications

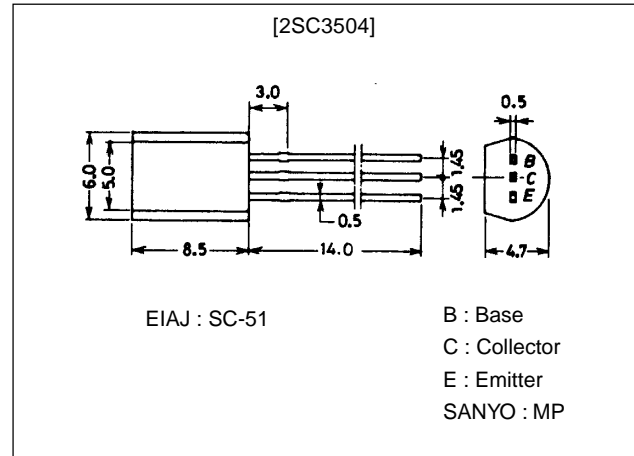
Features

- High f_T .
- Small reverse transfer capacitance.

Package Dimensions

unit:mm

2006A



Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Condition	Rating	Unit
Collector-to-Base Voltage	V_{CB}		70	V
Collector-to-Emitter Voltage	V_{CE}		60	V
Emitter-to-Base Voltage	V_{EB}		4	V
Collector Current	I_C		50	mA
Collector Current (Pulse)	I_{CP}		100	mA
Collector Dissipation	P_C		900	mW
Junction Temperature	T_j		150	$^\circ\text{C}$
Storage Temperature	T_{st}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB}=40\text{V}, I_E=0$			0A	μ
Emitter Cutoff Current	I_{EBO}	$V_{EB}=3\text{V}, I_C=0$			1A	μ
DC Current Gain	h_{FE}	$V_{CE}=10\text{V}, I_C=10\text{mA}$	60*		320	
Gain-Bandwidth Product	f_T	$V_{CE}=10\text{V}, I_C=10\text{mA}$	300	50		MH
Base-to-Collector Time Constant	t_{bc}	$V_{CE}=10\text{V}, I_C=10\text{mA}$		80	2s	p
Reverse Transfer Capacitance	C_{tr}	$V_{CB}=0\text{V}, f=1\text{MHz}$		16	1F	p
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=20\text{mA}, I_B=2\text{mA}$			0.5	V
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C=20\text{mA}, I_B=0\text{mA}$			1.0	V

* : The 2SC3504 is classified by 10mA h_{FE} as follows :

60	D	120	100	E	200	160	F	320
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■ Any and all SANYO products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO representative nearest you before using any SANYO products described or contained herein in such applications.

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2SC3504

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Base Breakdown Voltage	(BR)CBO	$I_C=10\mu A, I_E=0$	7V			
Collector-to-Emitter Breakdown Voltage	(BR)CEO	$I_C=1mA, R_{BE}=\infty$	6V			
Emitter-to-Base Breakdown Voltage	(BR)EBO	$I_E=10\mu A, I_C=0$				V

